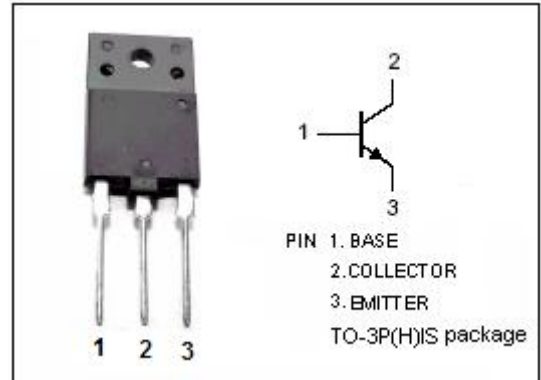


isc Silicon NPN Power Transistor
BU2507AX
DESCRIPTION

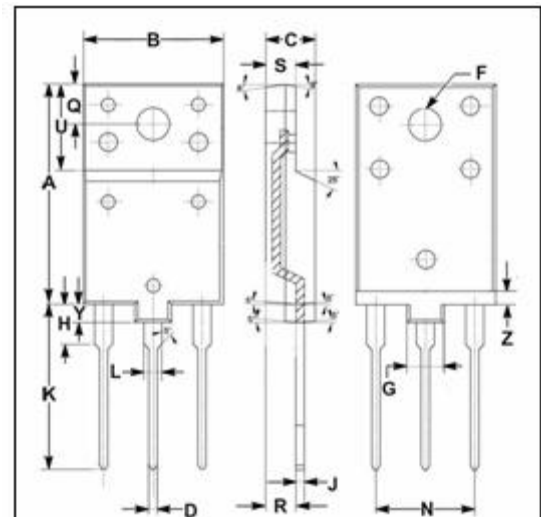
- High Switching Speed
- High Voltage
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

- Designed for use in horizontal deflection circuits of colour TV receivers and computer monitors.


ABSOLUTE MAXIMUM RATINGS ($T_a=25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{CESM}	Collector-Emitter Voltage $V_{BE}=0$	1500	V
V_{CEO}	Collector-Emitter Voltage	700	V
V_{EBO}	Emitter-Base Voltage	7.5	V
I_C	Collector Current-Continuous	8	A
I_{CM}	Collector Current-peak	15	A
I_B	Base Current-Continuous	4	A
I_{BM}	Base Current-peak	6	A
P_C	Collector Power Dissipation @ $T_c=25^\circ\text{C}$	45	W
T_j	Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature Range	-65~150	$^\circ\text{C}$



DIM	mm	
	MIN	MAX
A	24.10	24.70
B	15.20	15.80
C	5.20	5.80
D	0.65	1.05
F	3.30	3.90
G	3.90	4.10
H	4.30	4.70
J	0.80	1.00
K	18.30	18.70
L	1.90	2.40
N	10.70	11.10
Q	4.40	4.60
R	3.30	3.70
S	3.20	3.40
U	9.50	9.70
Y	1.90	2.10
Z	1.40	1.60

THERMAL CHARACTERISTICS


SYMBOL	PARAMETER	MAX	UNIT
$R_{th\ j-c}$	Thermal Resistance, Junction to Case	2.8	K/W

isc Silicon NPN Power Transistor

BU2507AX

ELECTRICAL CHARACTERISTICS

T_c=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{CEO(SUS)}	Collector-Emitter Sustaining Voltage	I _C = 50mA ; I _B = 0, L= 25mH	700			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 1mA; I _C = 0	7.5			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 4A ; I _B = 0.8A			5.0	V
V _{BE(sat)}	Base-Emitter Saturation Voltage 	I _C = 4A ; I _B = 0.8A			1.1	V
I _{CES}	Collector Cutoff Current	V _{CE} = BV _{CES} ; V _{BE} = 0 V _{CE} = BV _{CES} ; V _{BE} = 0; T _C =125°C			1.0 2.0	mA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 7.5V; I _C = 0			1.0	mA
h _{FE-1}	DC Current Gain	I _C = 100mA; V _{CE} = 5V		17		
h _{FE-2}	DC Current Gain	I _C = 4A; V _{CE} = 5V	5	7	9	
C _{OB}	Output Capacitance	I _E = 0; V _{CB} = 10V; f _{test} = 1MHz		68		pF

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